JUL 2 9 2004

C1 .		-		
Sheet	ı	of	1	

	18										
Form PTO-1449 (REV. 8-83)				ATTY DOCKET NO. 107291			APPLICATION NO. 09/701,534				
INFORMATION DISCLOSURE STATEMENT											
(Use several sheets if necessary)				APPLICANT(S) Shunichi SEKI et al.							
				FILING DATE November 30, 2000			GROUP 1762				
U.S. PATE					ENT DOCUMENTS			1702			
EXAMINER INITIAL	MINER					214.147			SUB		
INITIAL		DOCUMENT NUMBER [		DATE NA		NAME	NAME CLA		CLASS		
	<del> </del> -										
				_							
									· · · · · · · · · · · · · · · · · · ·		
			· · ·								
			···								
		FOREIGN	PATEN	T DO	CUMENTS			L			
		DOCUMENT NUMBER			DATE	COUNTRY		CI ACC	SUB		
M30	1	GB 2 077 710 A		12/23/1981		Great Britain		CLASS	CLASS		
PIBE	2	JP-A 64-029661 w/ Abstract		01/31/1989 Ja		Japan					
MBO	3	JP-A 09-237927 w/ Abstract and translation		09/09/1997 Jap		Japan		-			
MBP	4	JP-A 63-111454 w/ Abstract		05/16/1988 Japan		Japan					
Sype	5	JP-A 10-321536 w/ Abstract and translation		12/04/1998 Japa		Japan					
		OTHER DOCUMENTS (Inclu	ding Aut	thor, T	itle, Date, Pert	inent Pages, etc.)		L			
M30	6	"Advances in deposition Processes for Passivation Films", W. Kern et al., J. Vac. Sci. Technology, 14, 1082, ©1977.									
groce.	7	"Substitutional doping of Amorphous Silicon", W. E. Spear et al., Solid State Communications, 17, 1193, ©1975.									
:				-	· · · · · · · · · · · · · · · · · · ·		· · · · ·				
		- 1 /	<u>"</u>								
EXAMINER DATE CONSIDERED 9/15/67											
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.											

Date: July 29, 2004